

**[ABSTRACT]**

TITLE

**Thin Film Inorganic Light Emitting Diode**

A method for the manufacturing of a Thin Film Inorganic Light Emitting Diode is disclosed. The device contains in one single layer or in a double layer a dispersion of zinc sulfide doped with a luminescent centre, and a water-compatible p-type semiconductive polymer, preferably a polythiophene/polymeric polyanion complex.

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